

# 74LVC2GU04

## Dual inverter

Rev. 6 — 27 October 2010

Product data sheet

## 1. General description

The 74LVC2GU04 provides two inverters. Each inverter is a single stage with unbuffered output.

The inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

## 2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant input/output for interfacing with 5 V logic
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- $\pm 24$  mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Input accepts voltages up to 5 V
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and  $-40$  °C to  $+125$  °C

## 3. Ordering information

Table 1. Ordering information

| Type number  | Package               |       |   |         |
|--------------|-----------------------|-------|---|---------|
|              | Temperature range     | Name  | Description   | Version |
| 74LVC2GU04GW | $-40$ °C to $+125$ °C | SC-88 | plastic surface-mounted package; 6 leads  | SOT363  |
| 74LVC2GU04GV | $-40$ °C to $+125$ °C | TSOP6 | plastic surface-mounted package (TSOP6); 6 leads  | SOT457  |
| 74LVC2GU04GM | $-40$ °C to $+125$ °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1.45 \times 0.5$ mm | SOT886  |
| 74LVC2GU04GF | $-40$ °C to $+125$ °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1 \times 0.5$ mm    | SOT891  |
| 74LVC2GU04GN | $-40$ °C to $+125$ °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm       | SOT1115 |
| 74LVC2GU04GS | $-40$ °C to $+125$ °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm       | SOT1202 |



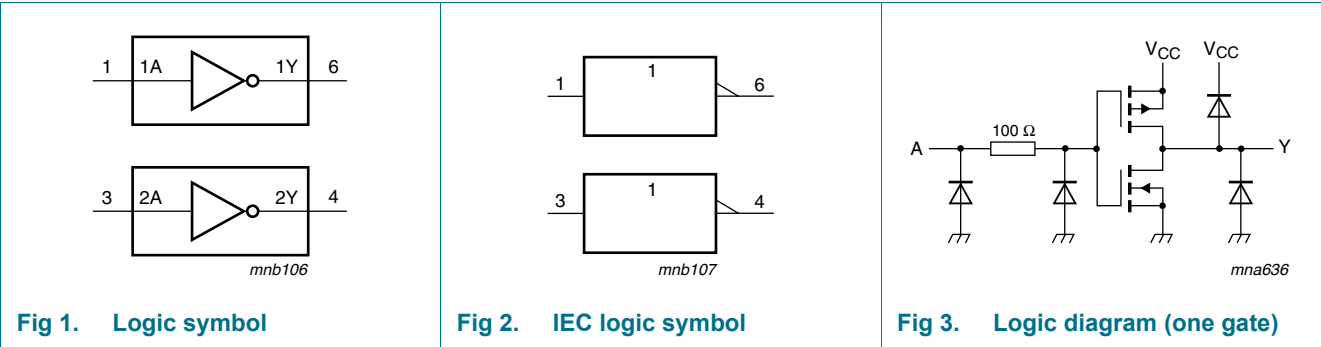
4. Marking

Table 2. Marking codes

| Type number  | Marking <sup>[1]</sup> |
|--------------|------------------------|
| 74LVC2GU04GW | YD                     |
| 74LVC2GU04GV | VU4                    |
| 74LVC2GU04GM | YD                     |
| 74LVC2GU04GF | YD                     |
| 74LVC2GU04GN | YD                     |
| 74LVC2GU04GS | YD                     |

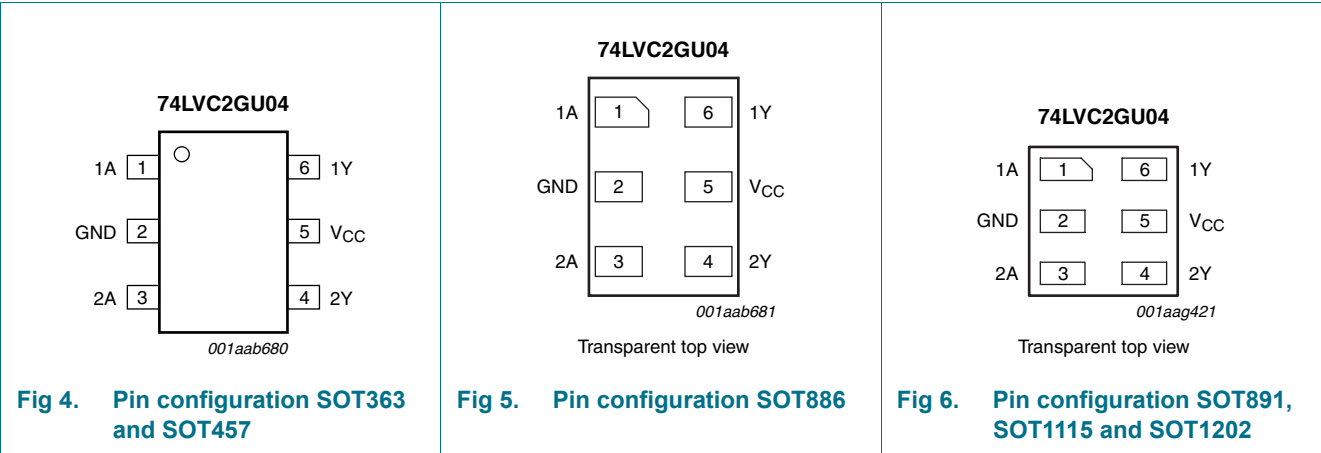
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



## 6.2 Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| 1A              | 1   | data input     |
| GND             | 2   | ground (0 V)   |
| 2A              | 3   | data input     |
| 2Y              | 4   | data output    |
| V <sub>CC</sub> | 5   | supply voltage |
| 1Y              | 6   | data output    |

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | H      |
| H     | L      |

[1] H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                              | Min                    | Max                   | Unit |
|------------------|-------------------------|---|------------------------|-----------------------|------|
| V <sub>CC</sub>  | supply voltage          |   | -0.5                   | +6.5                  | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V                    | -50                    | -                     | mA   |
| V <sub>I</sub>   | input voltage           |   | <sup>[1]</sup> -0.5    | +6.5                  | V    |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> < 0 V                    | -50                    | -                     | mA   |
| V <sub>O</sub>   | output voltage          | Active mode                             | <sup>[1][2]</sup> -0.5 | V <sub>CC</sub> + 0.5 | V    |
| I <sub>O</sub>   | output current          | V <sub>O</sub> = 0 V to V <sub>CC</sub> | -                      | ±50                   | mA   |
| I <sub>CC</sub>  | supply current          |   | -                      | 100                   | mA   |
| I <sub>GND</sub> | ground current          |   | -100                   | -                     | mA   |
| T <sub>stg</sub> | storage temperature     |   | -65                    | +150                  | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C    | <sup>[3]</sup> -       | 250                   | mW   |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When V<sub>CC</sub> = 0 V (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For SC-88 and SC-74 packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.  
For XSON6 packages: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

Voltages are referenced to GND (ground = 0 V).

| Symbol              | Parameter                           | Conditions                                  | Min  | Typ | Max      | Unit |
|---------------------|-------------------------------------|---|------|-----|----------|------|
| $V_{CC}$            | supply voltage                      |   | 1.65 | -   | 5.5      | V    |
| $V_I$               | input voltage                       |   | 0    | -   | 5.5      | V    |
| $V_O$               | output voltage                      | Active mode                                 | 0    | -   | $V_{CC}$ | V    |
| $T_{amb}$           | ambient temperature                 |   | -40  | -   | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$ | -    | -   | 20       | ns/V |
|                     |                                     | $V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}$  | -    | -   | 10       | ns/V |

## 10. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol  | Parameter                 | Conditions  | Min                  | Typ       | Max                  | Unit          |
|---|---------------------------|---|----------------------|-----------|----------------------|---------------|
| $T_{amb} = -40 \text{ °C to } +85 \text{ °C}$ [1] |                           |   |                      |           |                      |               |
| $V_{IH}$  | HIGH-level input voltage  | $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$   | $0.75 \times V_{CC}$ | -         | -                    | V             |
| $V_{IL}$  | LOW-level input voltage   | $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$   | -                    | -         | $0.25 \times V_{CC}$ | V             |
| $V_{OH}$  | HIGH-level output voltage | $V_I = V_{IH} \text{ or } V_{IL}$   |                      |           |                      |               |
|   |                           | $I_O = -100 \text{ }\mu\text{A};$<br>$V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$                | $V_{CC} - 0.1$       | -         | -                    | V             |
|   |                           | $I_O = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$  | 1.2                  | -         | -                    | V             |
|   |                           | $I_O = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$   | 1.9                  | -         | -                    | V             |
|   |                           | $I_O = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$  | 2.2                  | -         | -                    | V             |
|   |                           | $I_O = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$  | 2.3                  | -         | -                    | V             |
|   |                           | $I_O = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$  | 3.8                  | -         | -                    | V             |
| $V_{OL}$  | LOW-level output voltage  | $V_I = V_{IH} \text{ or } V_{IL}$   |                      |           |                      |               |
|   |                           | $I_O = 100 \text{ }\mu\text{A};$<br>$V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$                 | -                    | -         | 0.1                  | V             |
|   |                           | $I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$   | -                    | -         | 0.45                 | V             |
|   |                           | $I_O = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$  | -                    | -         | 0.3                  | V             |
|   |                           | $I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$   | -                    | -         | 0.4                  | V             |
|   |                           | $I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$   | -                    | -         | 0.55                 | V             |
|   |                           | $I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$   | -                    | -         | 0.55                 | V             |
| $I_I$   | input leakage current     | $V_I = 5.5 \text{ V or GND};$<br>$V_{CC} = 0 \text{ V to } 5.5 \text{ V}$                       | [2] -                | $\pm 0.1$ | $\pm 5$              | $\mu\text{A}$ |
| $I_{CC}$  | supply current            | $V_I = 5.5 \text{ V or GND}; I_O = 0 \text{ A};$<br>$V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$ | -                    | 0.1       | 10                   | $\mu\text{A}$ |
| $C_I$   | input capacitance         | $V_{CC} = 3.3 \text{ V}; V_I = \text{GND to } V_{CC}$   | -                    | 5         | -                    | pF            |

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

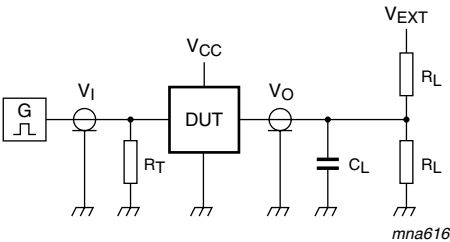
| Symbol                                     | Parameter                 | Conditions  | Min                   | Typ | Max                   | Unit |
|--|---------------------------|---|-----------------------|-----|-----------------------|------|
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                           |   |                       |     |                       |      |
| V <sub>IH</sub>                            | HIGH-level input voltage  | V <sub>CC</sub> = 1.65 V to 5.5 V   | 0.8 × V <sub>CC</sub> | -   | -                     | V    |
| V <sub>IL</sub>                            | LOW-level input voltage   | V <sub>CC</sub> = 1.65 V to 5.5 V   | -                     | -   | 0.2 × V <sub>CC</sub> | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                       |                       |     |                       |      |
|  |                           | I <sub>O</sub> = -100 µA;<br>V <sub>CC</sub> = 1.65 V to 5.5 V                            | V <sub>CC</sub> - 0.1 | -   | -                     | V    |
|  |                           | I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V  | 0.95                  | -   | -                     | V    |
|  |                           | I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V   | 1.7                   | -   | -                     | V    |
|  |                           | I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V  | 1.9                   | -   | -                     | V    |
|  |                           | I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V  | 2.0                   | -   | -                     | V    |
|  |                           | I <sub>O</sub> = -32 mA; V <sub>CC</sub> = 4.5 V  | 3.4                   | -   | -                     | V    |
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                       |                       |     |                       |      |
|  |                           | I <sub>O</sub> = 100 µA;<br>V <sub>CC</sub> = 1.65 V to 5.5 V                             | -                     | -   | 0.1                   | V    |
|  |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V   | -                     | -   | 0.7                   | V    |
|  |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V  | -                     | -   | 0.45                  | V    |
|  |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V   | -                     | -   | 0.6                   | V    |
|  |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V   | -                     | -   | 0.8                   | V    |
|  |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V   | -                     | -   | 0.8                   | V    |
| I <sub>I</sub>                             | input leakage current     | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V                          | -                     | -   | ±20                   | µA   |
| I <sub>CC</sub>                            | supply current            | V <sub>I</sub> = 5.5 V or GND; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 1.65 V to 5.5 V | -                     | -   | 40                    | µA   |

[1] All typical values are measured at T<sub>amb</sub> = 25 °C.[2] These typical values are measured at V<sub>CC</sub> = 3.3 V.



Table 9. Measurement points

| Supply voltage   | Input                 | Output                |
|------------------|-----------------------|-----------------------|
| V <sub>CC</sub>  | V <sub>M</sub>        | V <sub>M</sub>        |
| 1.65 V to 1.95 V | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 2.3 V to 2.7 V   | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 2.7 V            | 1.5 V                 | 1.5 V                 |
| 3.0 V to 3.6 V   | 1.5 V                 | 1.5 V                 |
| 4.5 V to 5.5 V   | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |



Test data is given in [Table 10](#).  
Definitions for test circuit:  
R<sub>L</sub> = Load resistance.  
C<sub>L</sub> = Load capacitance including jig and probe capacitance.  
R<sub>T</sub> = Termination resistance should be equal to the output impedance Z<sub>o</sub> of the pulse generator.  
V<sub>EXT</sub> = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage   | Input           |                                 | Load           |                | V <sub>EXT</sub>                    |
|------------------|-----------------|---------------------------------|----------------|----------------|-------------------------------------|
| V <sub>CC</sub>  | V <sub>I</sub>  | t <sub>r</sub> = t <sub>f</sub> | C <sub>L</sub> | R <sub>L</sub> | t <sub>PLH</sub> , t <sub>PHL</sub> |
| 1.65 V to 1.95 V | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF          | 1 kΩ           | open                                |
| 2.3 V to 2.7 V   | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF          | 500 Ω          | open                                |
| 2.7 V            | 2.7 V           | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | open                                |
| 3.0 V to 3.6 V   | 2.7 V           | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | open                                |
| 4.5 V to 5.5 V   | V <sub>CC</sub> | ≤ 2.5 ns                        | 50 pF          | 500 Ω          | open                                |

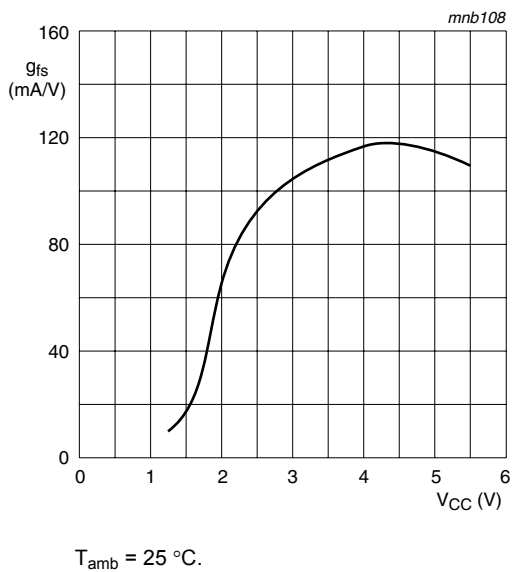
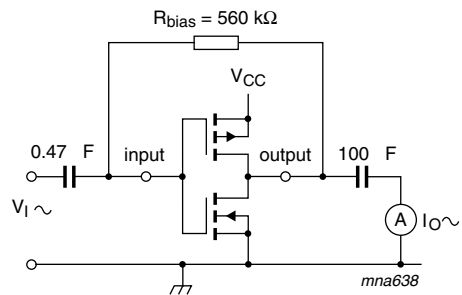


Fig 9. Typical forward transconductance as a function of supply voltage



$$g_{fs} = \frac{\Delta I_O}{\Delta V_I}$$

$f_i = 1\text{ kHz}.$

$V_O$  is constant.

Fig 10. Test set-up for measuring forward transconductance

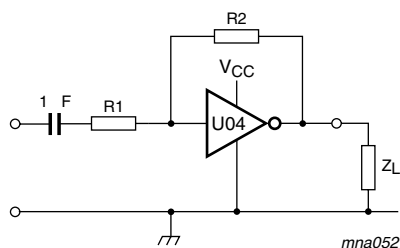


### 13. Application information

Some applications are:

- Linear amplifier (see [Figure 11](#))
- In crystal oscillator design (see [Figure 12](#))

**Remark:** All values given are typical unless otherwise specified.



$$V_{o(p-p)} = V_{CC} - 1.5 \text{ V centered at } 0.5V_{CC}.$$

$$A_u = -\frac{G_{OL}}{1 + \frac{R1}{R2}(1 + G_{OL})}$$

$G_{OL}$  = open loop gain.

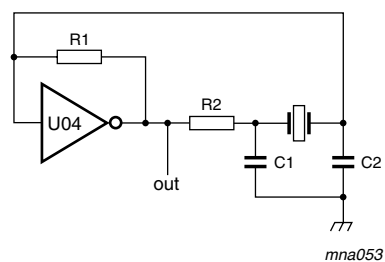
$A_u$  = voltage amplification.

$R1 \geq 3 \text{ k}\Omega$ ,  $R2 \leq 1 \text{ M}\Omega$ .

$Z_L > 10 \text{ k}\Omega$ ;  $A_{OL} = 20$  (typical).

Typical unity gain bandwidth product is 5 MHz.

**Fig 11. Linear amplifier configuration**



$C1 = 47 \text{ pF}$  (typical).

$C2 = 22 \text{ pF}$  (typical).

$R1 = 1 \text{ M}\Omega$  to  $10 \text{ M}\Omega$  (typical).

$R2$  optimum value depends on the frequency and required stability against changes in  $V_{CC}$  or average minimum  $I_{CC}$  ( $I_{CC}$  is typically 2 mA at  $V_{CC} = 3.3 \text{ V}$  and  $f = 10 \text{ MHz}$ ).

**Fig 12. Crystal oscillator configuration**

# 14. Package outline

Plastic surface-mounted package; 6 leads

SOT363

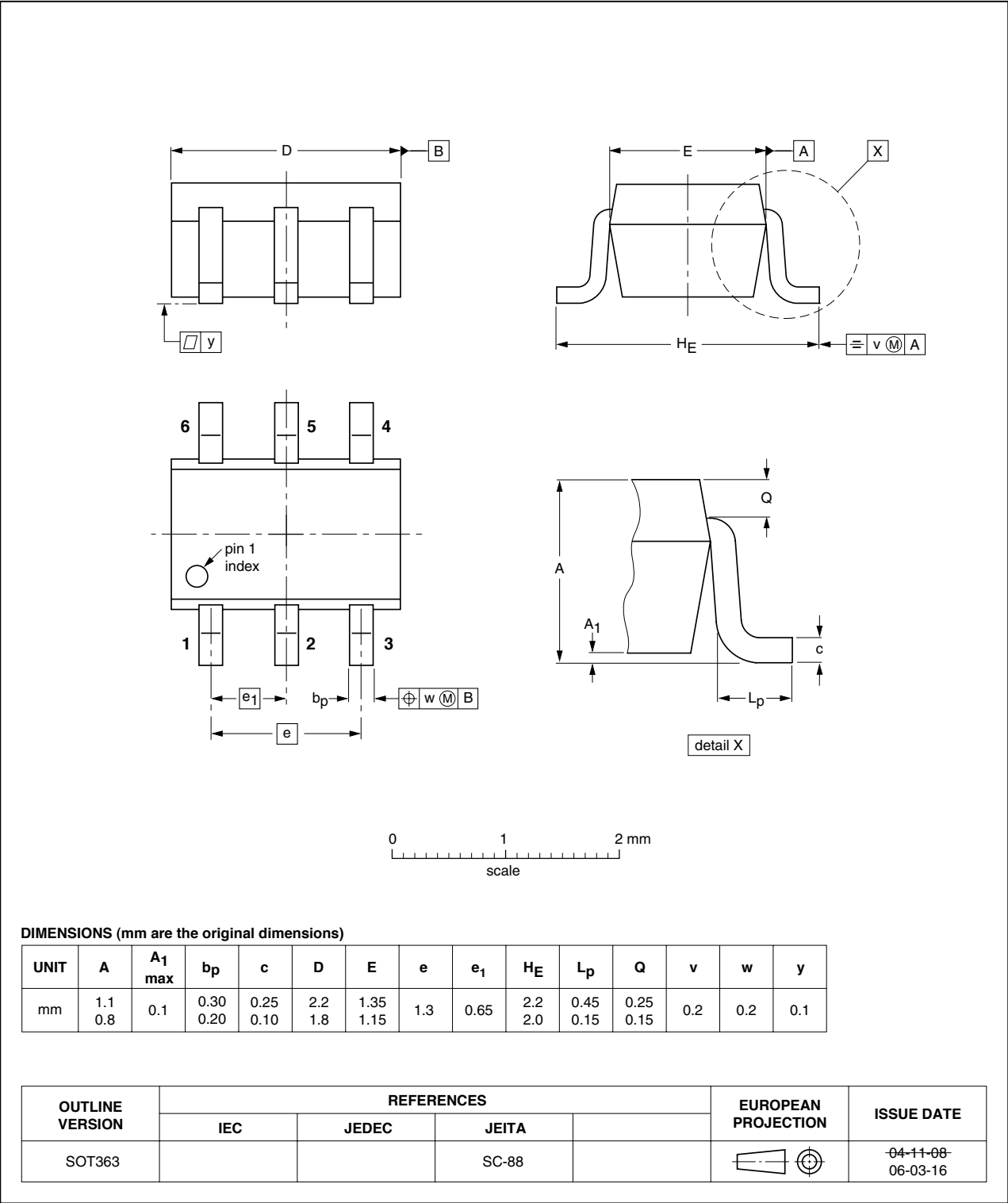


Fig 13. Package outline SOT363 (SC-88)

Plastic surface-mounted package (TSOP6); 6 leads

SOT457

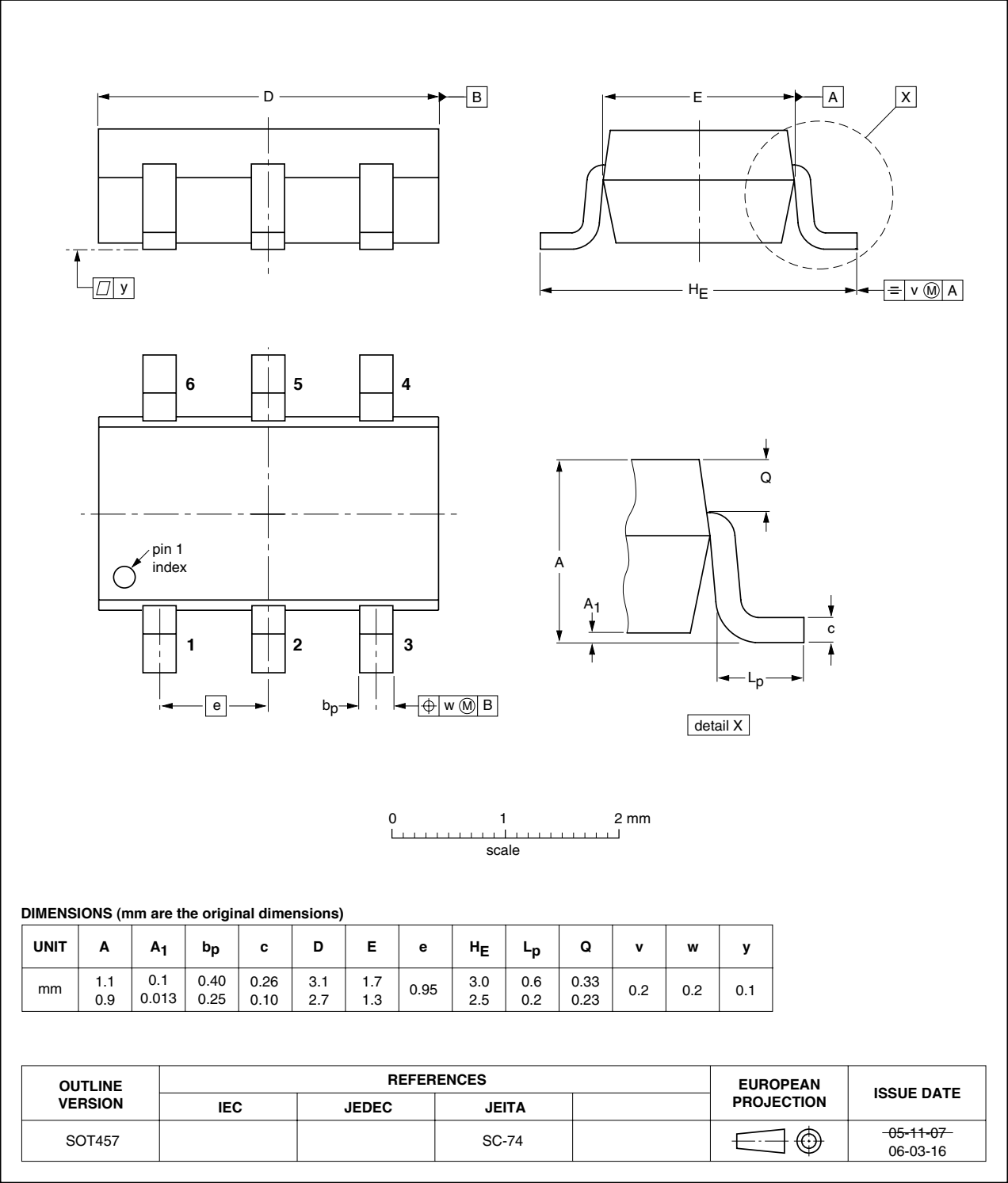


Fig 14. Package outline SOT457 (TSOP6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

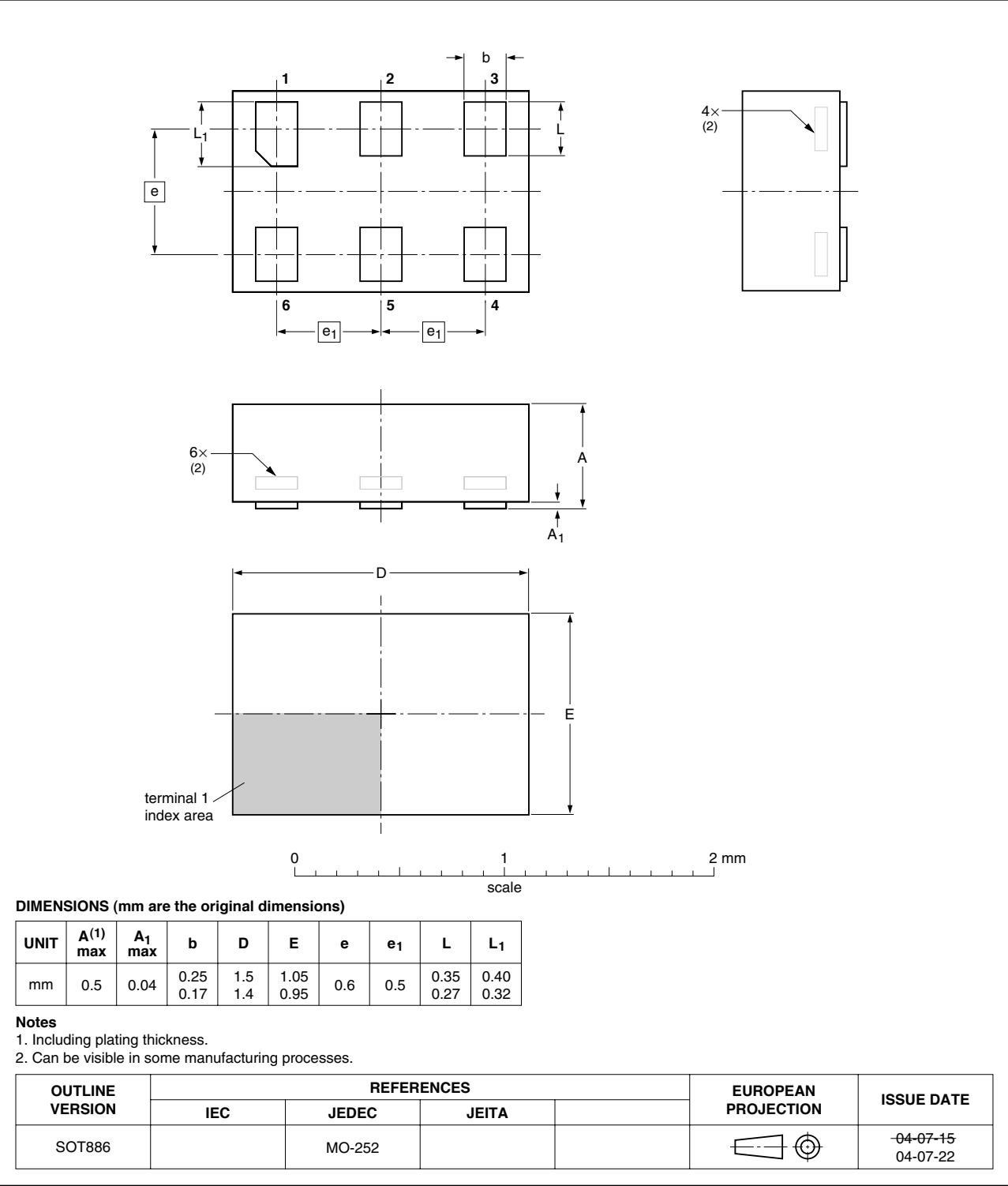


Fig 15. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

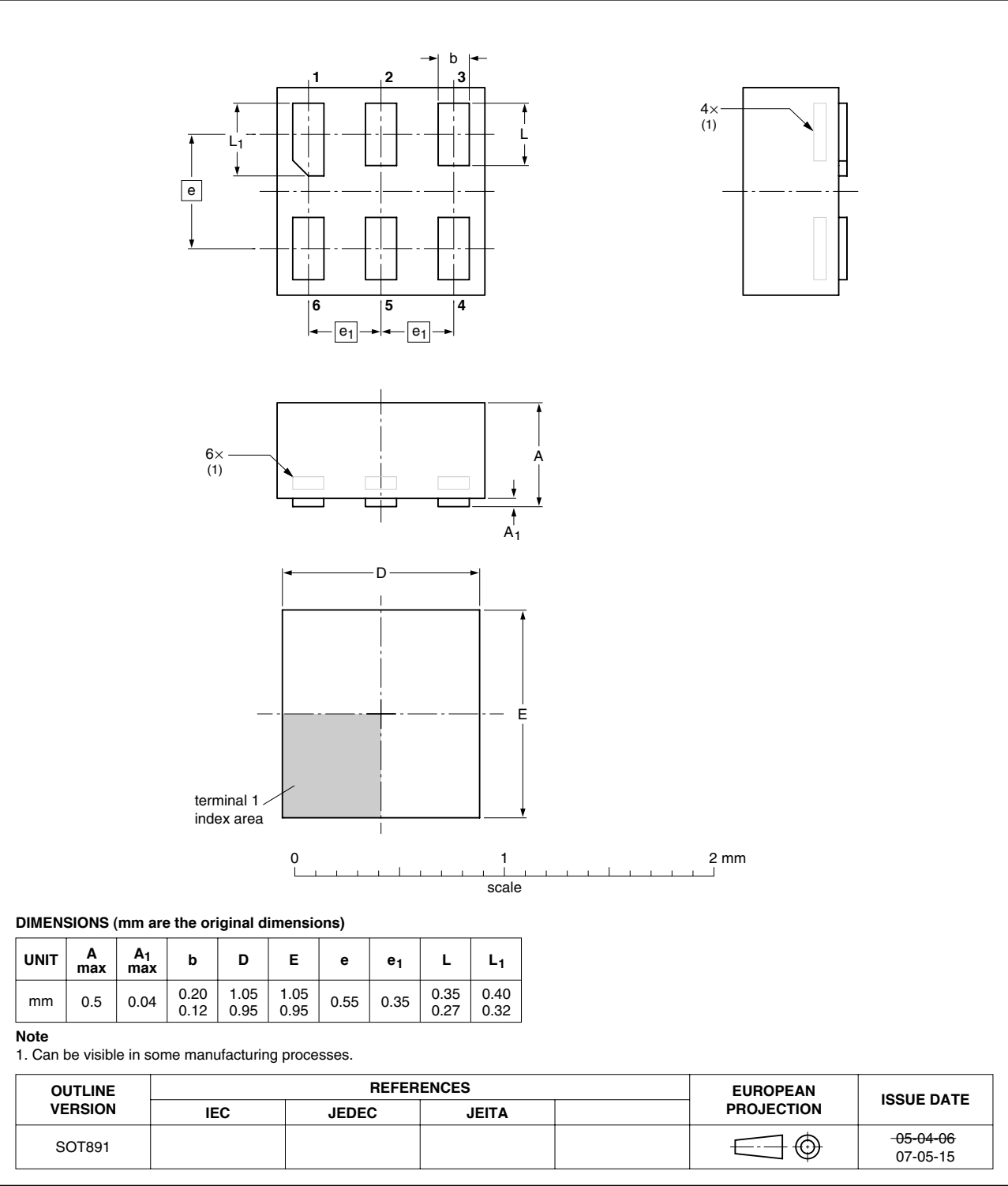
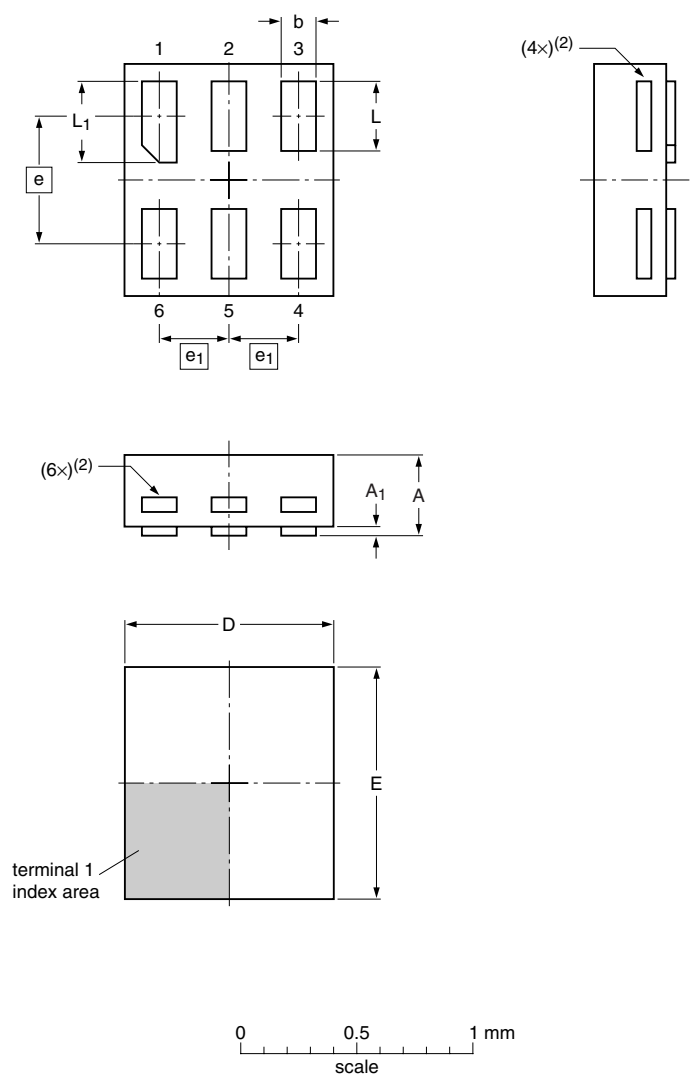


Fig 16. Package outline SOT891 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 0.9 x 1.0 x 0.35 mm

SOT1115



Dimensions

| Unit | A <sup>(1)</sup> | A <sub>1</sub> | b    | D    | E    | e    | e <sub>1</sub> | L    | L <sub>1</sub> |
|------|------------------|----------------|------|------|------|------|----------------|------|----------------|
| mm   | max              | 0.35           | 0.04 | 0.20 | 0.95 | 1.05 |                | 0.35 | 0.40           |
|      | nom              |                |      | 0.15 | 0.90 | 1.00 | 0.55           | 0.30 | 0.35           |
|      | min              |                |      | 0.12 | 0.85 | 0.95 |                | 0.27 | 0.32           |

- Note
- 1. Including plating thickness.
  - 2. Visible depending upon used manufacturing technology.

sot1115\_po

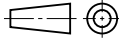
| Outline version | References |       |       |  | European projection   | Issue date                      |
|-----------------|------------|-------|-------|--|---|---------------------------------|
|                 | IEC        | JEDEC | JEITA |  |   |                                 |
| SOT1115         |            |       |       |  |  | <del>10-04-02</del><br>10-04-07 |

Fig 17. Package outline SOT1115 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 1.0 x 1.0 x 0.35 mm

SOT1202

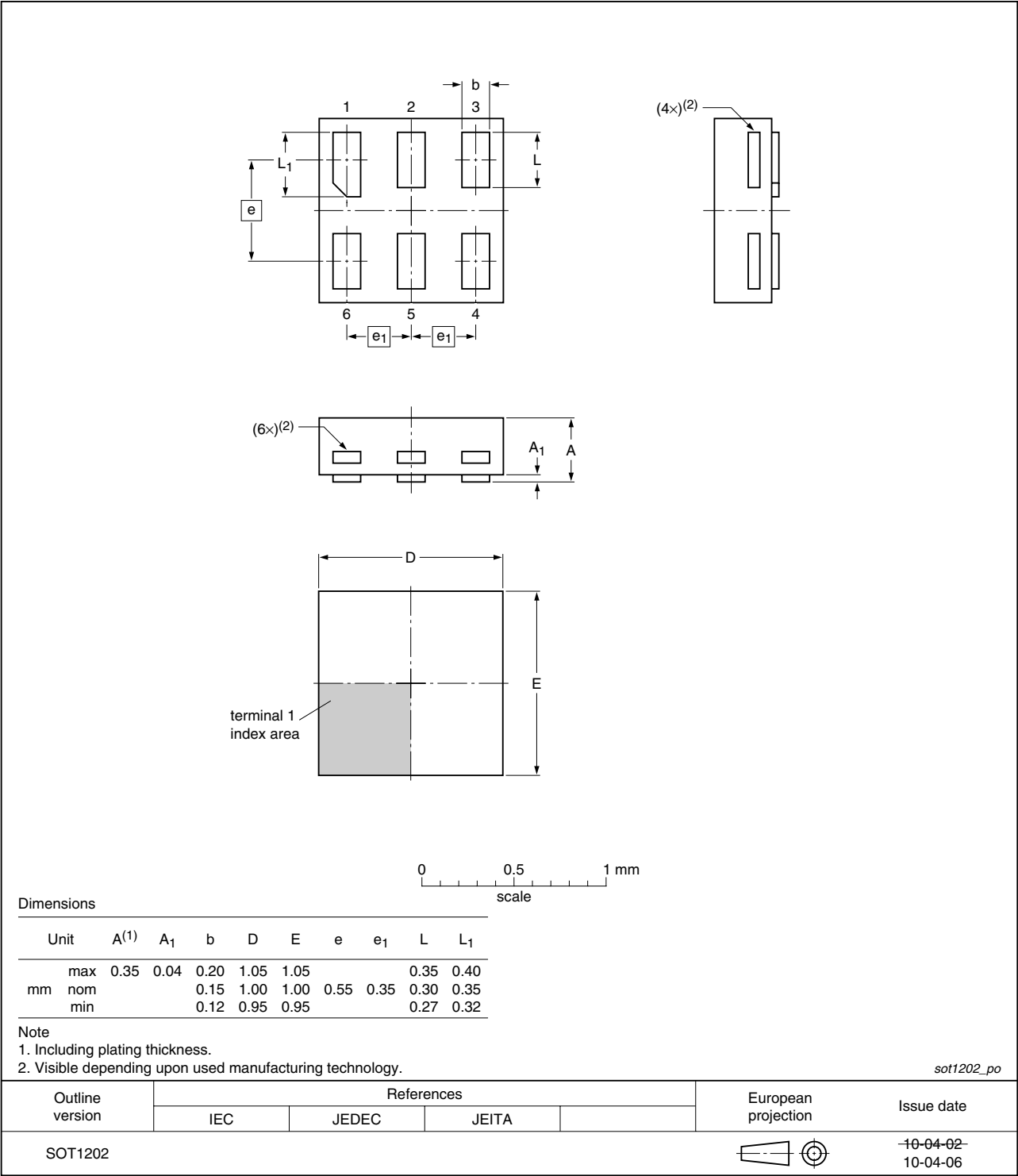


Fig 18. Package outline SOT1202 (XSON6)

## 15. Abbreviations

Table 11. Abbreviations

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |

## 16. Revision history

Table 12. Revision history

| Document ID    | Release date  | Data sheet status     | Change notice | Supersedes     |
|----------------|---|-----------------------|---------------|----------------|
| 74LVC2GU04 v.6 | 20101027  | Product data sheet    | -             | 74LVC2GU04 v.5 |
| Modifications: | <ul style="list-style-type: none"><li>Added type number 74LVC2GU04GN (SOT1115/XSON6 package).</li><li>Added type number 74LVC2GU04GS (SOT1202/XSON6 package).</li></ul> |                       |               |                |
| 74LVC2GU04 v.5 | 20091027  | Product data sheet    | -             | 74LVC2GU04 v.4 |
| 74LVC2GU04 v.4 | 20070521  | Product data sheet    | -             | 74LVC2GU04 v.3 |
| 74LVC2GU04 v.3 | 20040921  | Product specification | -             | 74LVC2GU04 v.2 |
| 74LVC2GU04 v.2 | 20040524  | Product specification | -             | 74LVC2GU04 v.1 |
| 74LVC2GU04 v.1 | 20030829  | Product specification | -             | -              |



## 17. Legal information

### 17.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 17.2 Definitions

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